



PTO/SB/08A (10-01)

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Substitute for form 1448A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Complete If Known	
				Application Number	10/035,197
				Filing Date	January 4, 2002
				First Named Inventor	John Moore
				Art Unit	2185
				Examiner Name	Not Yet Assigned
Sheet	1	of	1	Attorney Docket Number	M4065.0488/P488

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
SD	A	6,469,364 B1	10/22/2002	Kozicki	
SD	B	US 2002/0168820 A1	11/14/2002	Kozicki et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)				

¹ Applicant's unique citation designation number (optional). ² See attached Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 801.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the application number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 18 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
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Examiner Signature	SON DINH	Date Considered	5/1/04
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¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

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		Country Code ² -Number ³ -Kind Code ⁴ (if known)				
CJ	BA	JP 56126916	10/1981	Akira et al.		
	BB					

Examiner Signature	SON DINH	Date Considered	5/1/04
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				First Named Inventor	John Moore
				Art Unit	2185
				Examiner Name	Not Yet Assigned
Sheet	2	of	4	Attorney Docket Number	M4065.0488/P488

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		Number-Kind Code ² (if known)			
CA	AA	6,469,364	10/2002	Kozicki	
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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Complete If Known			
		Application Number	10/193,529		
		Filing Date	July 10, 2002		
		First Named Inventor	Kristy A. Campbell		
		Group Art Unit	2714		
		Examiner Name	H. Weiss		
Sheet	4	of	4	Attorney Docket Number	M4065.0695/P695

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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CC	CC	Hill, DISSERTATION: <i>Materials characterization of Silver Chalcogenide Programmable Metalization Cells</i> , Arizona State University, pp. Title page-114 (UMI Company, May 1999).	
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CO	CO	Shimizu et al., <i>The Photo-Erasable Memory Switching Effect of Ag Photo-Doped Chalcogenide Glasses</i> , 46 B. CHEM SOC. JAPAN, No. 12, pp. 3662-3365 (1973).	
	CP		
	CQ		

Examiner Signature	SON DINH	Date Considered	5/1/04
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				Application Number	10/035,197-Conf. #2073
				Filing Date	January 4, 2002
				First Named Inventor	John Moore
				Art Unit	2824
				Examiner Name	S. T. Dinh
Sheet	1	of	1	Attorney Docket Number	M4065.0488/P488

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	CA	YOJI KAWAMOTO et al., "Ionic Conduction in As ₂ S ₃ -Ag ₂ S, GeS ₂ -GeS ₂ -GeS-Ag ₂ S and P ₂ S ₅ -Ag ₂ S Glasses," Journal of Non-Crystalline Solids 20 (1976) 393-404.	

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GD	CA	YOJI KAWAMOTO et al., "Ionic Conduction in As ₂ S ₃ -Ag ₂ S, GeS ₂ -GeS ₂ -GeS-Ag ₂ S and P ₂ S ₅ -Ag ₂ S Glasses," Journal of Non-Crystalline Solids 20 (1976) 393-404.	

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